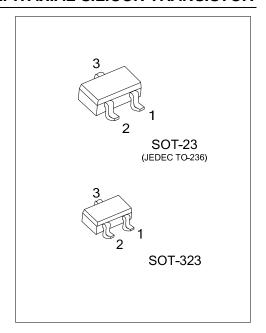
# DTA115E

# PNP EPITAXIAL SILICON TRANSISTOR

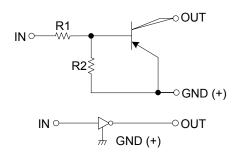
# PNP DIGITAL TRANSISTOR (BUILT-IN RESISTORS)

#### **■ FEATURES**

- \* Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see the equivalent circuit).
- \* The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input They also have the advantage of almost completely eliminating parasitic effects.
- \* Only the on / off conditions need to be set for operation, making device design easy.



#### **EQUIVALENT CIRCUIT**

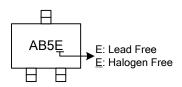


### ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
DTA115EL-AE3-R	DTA115EG-AE3-R	SOT-23	G	I	0	Tape Reel	
DTA115EL-AL3-R	DTA115EG-AL3-R	SOT-323	G	I	0	Tape Reel	

Note: Pin Assignment: G: GND I: IN O: OUT

#### **MARKING**



www.unisonic.com.tw 1 of 2 QW-R220-016,Ba

## ■ ABSOLUATE MAXIUM RATINGS (T<sub>A</sub>= 25°C, unless otherwise specified.)

PARAMETER	SYMBOL	RATINGS	UNIT	
Supply Voltage	V <sub>CC</sub>	-50	V	
Input Voltage	V <sub>IN</sub>	-40~+10	V	
0. 1. 1. 0	I <sub>OUT</sub>	-20	mA	
Output Current	I <sub>C(MAX)</sub>	-100		
Power Dissipation	$P_D$	200	mW	
Junction Temperature	TJ	150	$^{\circ}\mathbb{C}$	
Storage Temperature	T <sub>STG</sub>	-40 ~ +150	$^{\circ}\!\mathbb{C}$	

Note Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

### ■ ELECTRICAL CHARACTERISTICS (T<sub>A</sub>= 25°C, unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Input Voltage	V <sub>IN(OFF)</sub>	V <sub>CC</sub> = -5V, I <sub>OUT</sub> =-100μA			-0.5	V	
	V <sub>IN(ON)</sub>	$V_{OUT}$ = -0.3 $V_{IOUT}$ = -1mA	-3			V	
Output Voltage	V <sub>OUT(ON)</sub>	I <sub>OUT</sub> = -5mA, I <sub>IN</sub> = -0.25mA		-0.1	-0.3	V	
Input Current	I <sub>IN</sub>	V <sub>IN</sub> = -5V			-0.15	mA	
Output Current	I <sub>OUT(OFF)</sub>	V <sub>CC</sub> = -50V , V <sub>IN</sub> =0V			-0.5	μΑ	
DC Current Gain	Gı	$V_{OUT}$ = -5V, $I_{OUT}$ = -5mA	82				
Input Resistance	R <sub>1</sub>		70	100	130	kΩ	
Resistance Ratio	R <sub>2</sub> /R <sub>1</sub>		8.0	1	1.2		
Transition Frequency	$f_T$	V <sub>CE</sub> = -10 V, I <sub>E</sub> = 5mA, f=100MHz (Note)		250		MHz	

Note: Transition frequency of the device

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